NSN 5961-01-177-4723

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View Online at https://aerobasegroup.com/nsn/5961-01-177-4723 **Inclosure Material:** Metal **Overall Length:** 1.453 inches **End Application:** An/fps-117 radar system **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-5 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and quality assurance level tx **Overall Width Across Flats:** 0.687 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 65.1 breakdown voltage, dc **Voltage Tolerance In Percent:** -5.0/+5.0 **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current horsepower metric **Power Rating Per Characteristic:** 50.0 watts any acceptable preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud

N/a

Shelf Life:

Unit Of Measure:

Specification Data:

81349-mil-s-19500/358 government specification

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Demilitarization:

No

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